

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (MACH II π -MOS V)

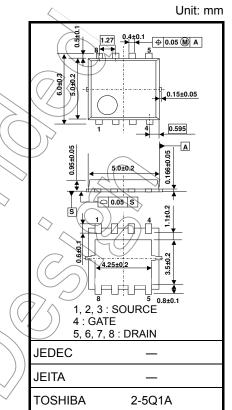
TPCA8009-H

High Speed Switching Applications Switching Regulator Applications DC/DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q_{SW} = 3.7 nC (typ.)
- Low drain-source ON-resistance: $RDS(ON) = 0.23\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.5S$ (typ.)
- Low leakage current: $I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 150 \ V)$
- Enhancement mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

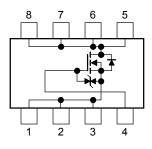
Absolute Maximum Ratings (Ta = 25°C)

			$\langle \circ \rangle$	~
Characte	ristic	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	150	V
Drain-gate voltage (R	l _{GS} = 20 kΩ)	V _{DGR}	150	X
Gate-source voltage		V _{GSS}	±20	< <v< td=""></v<>
Drain current	DC (Note 1)	ID	7	A
Drain current	Pulsed (Note 1)	LDP /	14	
Drain power dissipati	ower dissipation (Tc=25°C)		45	W
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	2.8	W
Drain power dissipati				W
Single-pulse avalanc	ne energy (Note 3)	EAS	34	mJ
Avalanche current		I _{AR}	7	А
	Repetitive avalanche energy (Tc=25°C) (Note 4)		1.5	mJ
Channel temperature		Tch	150	°C
Storage temperature	range	Tstg	–55 to 150	°C



Weight: 0.068 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

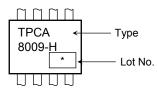
This transistor is an electrostatic-sensitive device. Handle with care.

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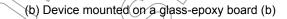
Thermal Characteristics

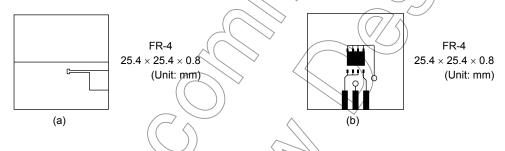
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	78.1	°C/W

Marking (Note 5)



- Note 1: The channel temperature should not exceed 150°C during use.
- Note 2: (a) Device mounted on a glass-epoxy board (a)





- Note 3: $V_{DD} = 50 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 1mH, R_G = 25 Ω , I_{AR} = 7 A
- Note 4: Repetitive rating: pulse width limited by max channel temperature
- Note 5: * Weekly code: (Three digits)



Electrical Characteristics (Ta = 25°C)

Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0~V$	_	_	±10	μA
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V	_		100	μA
		V (BR) DSS	I_D = 10 mA, V_{GS} = 0 V \langle	150			
Drain-source brea	akdown voltage		$I_D = 10 \text{ mA}, V_{GS} = -5 \text{ V}$	150			V
		V _(BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	100) /~(
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0	_	4.0	V
Drain-source ON-	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$	\mathcal{A}	0.23	0.35	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$	2.1	4.5	_	S
Input capacitance		C _{iss}			600	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	20		pF
Output capacitance		C _{oss}			220	\searrow	
	Rise time	tr		-(C	8	>	-
Rise timetr $V_{GS} \stackrel{10 V}{_{0 V}}$ $I_{D} = 3.5 \text{ A}$ 8Switching timeTurn-ON timeton $V_{GS} \stackrel{10 V}{_{0 V}}$ $V_{D} = 3.5 \text{ A}$ 17Fall timetf $V_{GS} \stackrel{10 V}{_{0 V}}$ V_{OLT} 13Turn-OFF timetoff $U_{UY} \le 1\%$, tw = 10 µs-70	Turn-ON time	t _{on}			17	_	
		ns					
	Turn-OFF time	toff	\bigcirc) —	70	_	
Total gate charge (gate-source plus		Qg	(((((((((((((((((((10		
Gate-source char	ge	Qgs	$V_{DD} \simeq 120 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$	_	7.6	_	
Gate-drain ("mille	r") charge	Qgd	$I_D = 7 A$	_	2.4	_	nC
Gate switch charg	ge	Qsw			3.7	_	

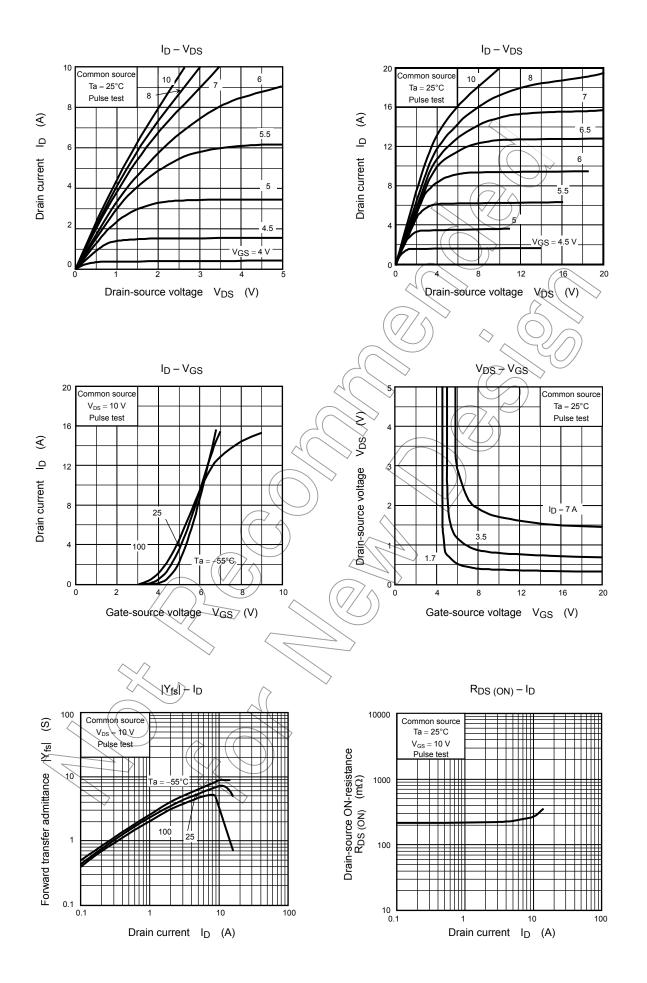
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol Test Condition		Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	IDRP	_	_	_	14	А
Forward voltage (diode)			VDSF	I _{DR} = 7 A, V _{GS} = 0 V	_		-2.0	V

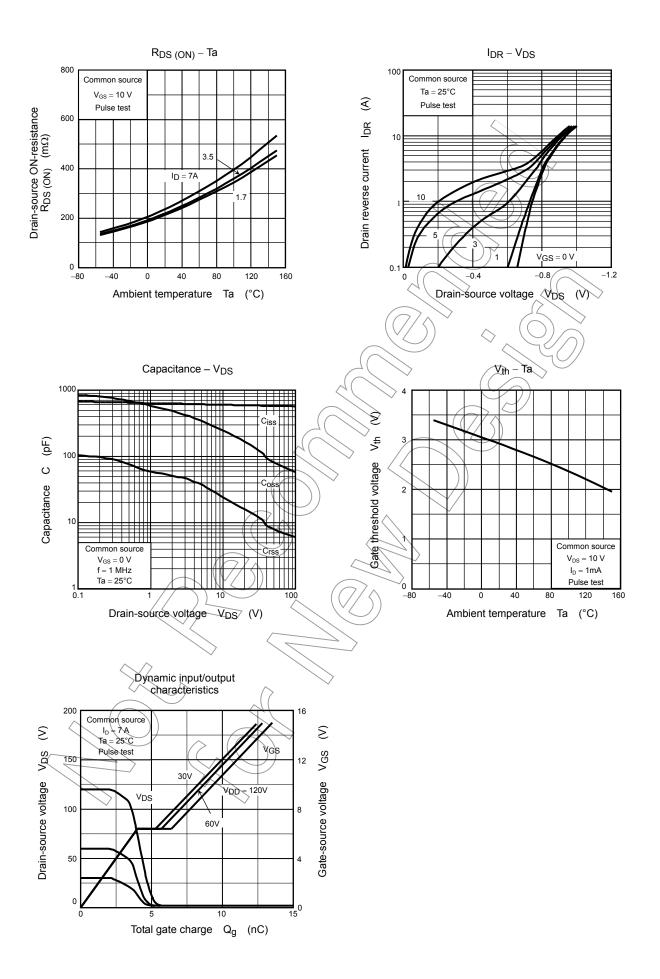


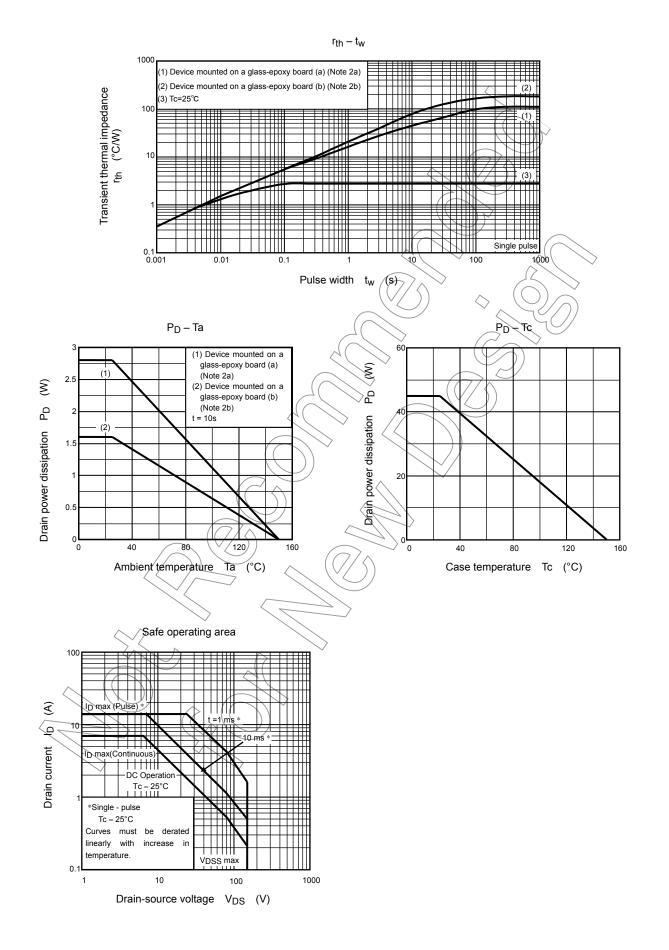


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